

1.0 Features

- Three output clock frequencies
- On-chip tunable voltage-controlled crystal oscillator (VCXO) allows precise system frequency tuning
- Wide crystal “pulling” range (typically 300ppm)
- VCXO tuning range from 0-3 volt
- 3.3V supply voltage (contact factory for 5V)
- Small circuit board footprint (8-pin 0.150” SOIC)
- Custom frequency selections available - contact your local AMI Sales Representative for more information

2.0 Description

The FS6182 is a monolithic CMOS clock generator IC designed to minimize cost and component count in digital video/audio systems.

At the core of the FS6182 is circuitry that implements a voltage-controlled crystal oscillator when an external resonator (nominally 13.5MHz) is attached. The VCXO allows device frequencies to be precisely adjusted for use in systems that have frequency matching requirements, such as digital satellite receivers.

A high-resolution phase-locked loop generates three output clocks (CLKA, CLKB, and CLKC) through an array of post-dividers. All frequencies are ratiometrically derived from the VCXO frequency. The locking of all the output frequencies together can eliminate unpredictable artifacts in video systems.

Figure 1: Pin Configuration

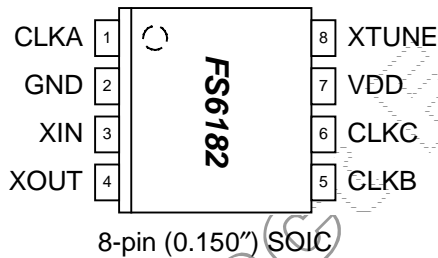


Table 1: Crystal / Output Frequencies

DEVICE	f _{XIN} (MHz)	CLKA (MHz)	CLKB (MHz)	CLKC (MHz)
FS6182-01	13.500	27.000	54.000	13.500

NOTE: Contact AMI for custom PLL frequencies and 5 volt operation

Figure 2: Block Diagram

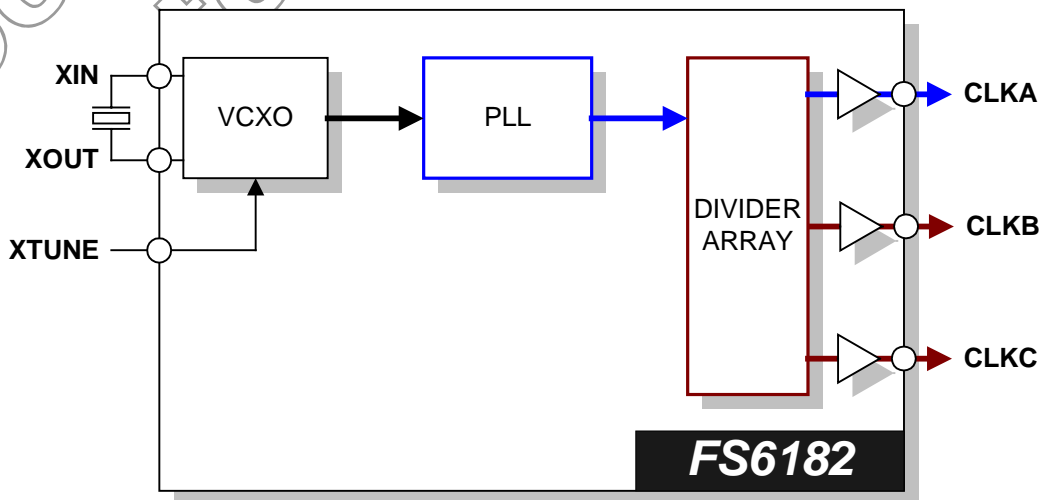


Table 2: Pin Descriptions

Key: AI = Analog Input; AO = Analog Output; DI = Digital Input; DI^U = Input with Internal Pull-Up; DI_D = Input with Internal Pull-Down; DIO = Digital Input/Output; DI-3 = Three-Level Digital Input, DO = Digital Output; P = Power/Ground; # = Active Low pin

PIN	TYPE	NAME	DESCRIPTION
1	DO	CLKA	Clock Output A
2	P	GND	Ground
3	AI	XIN	VCXO Feedback
4	AO	XOUT	VCXO Drive
5	DO	CLKB	Clock Output B
6	DO	CLKC	Clock Output C
7	P	VDD	Power Supply (+3.3V)
8	AI	XTUNE	VCXO Tune

3.0 Functional Block Description

3.1 Phase-Locked Loop (PLL)

The on-chip PLLs are a standard frequency- and phase-locked loop architecture. The PLL multiplies the reference oscillator to the desired frequency by a ratio of integers. The frequency multiplication is exact with a zero synthesis error.

3.2 Voltage-Controlled Crystal Oscillator (VCXO)

The VCXO provides a tunable, low-jitter frequency reference for the rest of the FS6182 system components. Loading capacitance for the crystal is internal to the FS6182. No external components (other than the resonator itself) are required for operation of the VCXO.

Continuous fine-tuning of the VCXO frequency is accomplished by varying the voltage on the XTUNE pin. The total change (from one extreme to the other) in effective loading capacitance is from 13pF to 35pF.

The oscillator operates the crystal resonator in the parallel-resonant mode. Crystal warping, or the “pulling” of the crystal oscillation frequency, is accomplished by altering the effective load capacitance presented to the crystal by

the oscillator circuit. The actual amount that changing the load capacitance alters the oscillator frequency will be dependent on the characteristics of the crystal as well as the oscillator circuit itself.

Specifically, the motional capacitance of the crystal (usually referred to by crystal manufacturers as C_1), the static capacitance of the crystal (C_0), and the load capacitance (C_L) of the oscillator determine the warping capability of the crystal in the oscillator circuit.

A simple formula to obtain the warping capability of a crystal oscillator is:

$$\Delta f (ppm) = \frac{C_1 \times (C_{L2} - C_{L1}) \times 10^6}{2 \times (C_0 + C_{L2}) \times (C_0 + C_{L1})}$$

where C_{L1} and C_{L2} are the two extremes of the applied load capacitance.

EXAMPLE: A crystal with the following parameters is used. With $C_1 = 0.02\text{pF}$, $C_0 = 5\text{pF}$, $C_{L1} = 13\text{pF}$, and $C_{L2} = 35\text{pF}$, the coarse tuning range (peak-to-peak) is:

$$\Delta f = \frac{0.02 \times (35 - 13) \times 10^6}{2 \times (5 + 35) \times (5 + 13)} = 305 \text{ ppm.}$$

4.0 Electrical Specifications

Table 3: Absolute Maximum Ratings

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These conditions represent a stress rating only, and functional operation of the device at these or any other conditions above the operational limits noted in this specification is not implied. Exposure to maximum rating conditions for extended conditions may affect device performance, functionality, and reliability.

PARAMETER	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage ($V_{SS} = \text{ground}$)	V_{DD}	$V_{SS}-0.5$	7	V
Input Voltage, dc	V_I	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Output Voltage, dc	V_O	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Input Clamp Current, dc ($V_I < 0$ or $V_I > V_{DD}$)	I_{IK}	-50	50	mA
Output Clamp Current, dc ($V_I < 0$ or $V_I > V_{DD}$)	I_{OK}	-50	50	mA
Storage Temperature Range (non-condensing)	T_S	-65	150	°C
Ambient Temperature Range, Under Bias	T_A	-55	125	°C
Junction Temperature	T_J		125	°C
Lead Temperature (soldering, 10s)			260	°C
Input Static Discharge Voltage Protection (MIL-STD 883E, Method 3015.7)			2	kV



CAUTION: ELECTROSTATIC SENSITIVE DEVICE

Permanent damage resulting in a loss of functionality or performance may occur if this device is subjected to a high-energy electrostatic discharge.

Table 4: Operating Conditions

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	MIN.	TYP.	MAX.	UNITS
Supply Voltage	V_{DD}	$3.3V \pm 10\%$	3.0	3.3	3.6	V
Ambient Operating Temperature Range	T_A		0		70	°C

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Table 5: DC Electrical Specifications

Unless otherwise stated, $V_{DD} = 3.3V \pm 10\%$, no load on any output, and ambient temperature range $T_A = 0^\circ C$ to $70^\circ C$. Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits. Where given, MIN and MAX characterization data are $\pm 3\sigma$ from typical. Negative currents indicate current flows out of the device.

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	MIN.	TYP.	MAX.	UNITS
Overall						
Supply Current, Dynamic, with Loaded Outputs	I_{DD}	$f_{XTAL} = 13.5MHz$; $C_L = 10pF$		20		mA
Voltage Controlled Crystal Oscillator						
Crystal Resonator Frequency	f_{XTAL}	Fundamental Mode	5	13.5	18	MHz
Crystal Loading Capacitance	$C_{L(xtal)}$	As seen by a crystal connected to XIN and XOUT (@ $V_{XTUNE} = \text{mid-range}$)		20		pF
Crystal Resonator Motional Capacitance	$C_{1(xtal)}$			20		fF
VCXO Tuning Range		$f_{XTAL} = 13.5MHz$; $C_L = 20pF$; $C_{MOT} = 25fF$		300		ppm
VCXO Tuning Characteristic		Note: positive delta F for positive delta V		100		ppm/V
Crystal Drive Level		$R_{XTAL} = 20\ ohm$; $C_L = 20pF$		200		uW
Clock Outputs (CLKA, CLKB, CLKC)						
High-Level Output Source Current *	I_{OH}	$V_O = 2.0V$		40		mA
Low-Level Output Sink Current *	I_{OL}	$V_O = 0.4V$		17		mA
Output Impedance *	Z_{OH}	$V_O = 0.1V_{DD}$; output driving high		25		Ω
	Z_{OL}	$V_O = 0.1V_{DD}$; output driving low		25		
Short Circuit Source Current *	I_{OSH}	$V_O = 0V$; shorted for 30s, max.		55		mA
Short Circuit Sink Current *	I_{OSL}	$V_O = 3.3V$; shorted for 30s, max.		55		mA

Table 6: AC Timing Specifications

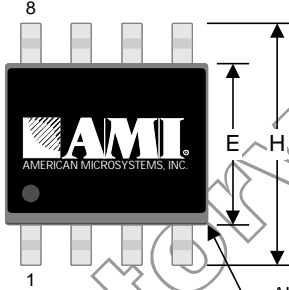
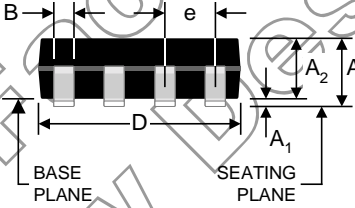
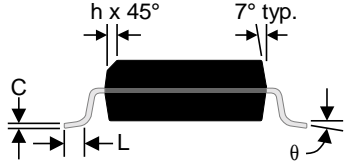
Unless otherwise stated, $V_{DD} = 3.3V \pm 10\%$, no load on any output, and ambient temperature range $T_A = 0^\circ C$ to $70^\circ C$. Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits. Where given, MIN and MAX characterization data are $\pm 3\sigma$ from typical.

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	MIN.	TYP.	MAX.	UNITS
Clock Outputs (CLKx)						
Duty Cycle *		t_{hi} / t_{clk} ; Measured at $V_{DD}/2$	43		57	%
Jitter, Absolute Period (pk-pk) *	$t_{j(\Delta P)}$	From rising edge to next rising edge at $V_{DD}/2$, $C_L = 10pF$		150		ps
Rise Time *	t_r	$V_{DD} = 3.3V$; $V_O = 0.3V$ to $3.0V$; $C_L = 10pF$		1		ns
Fall Time *	t_f	$V_{DD} = 3.3V$; $V_O = 3.0V$ to $0.3V$; $C_L = 10pF$		1		ns
Output Frequency Synthesis Error		(unless otherwise noted in Frequency Table)			0	ppm
VCXO Stabilization Time *	$t_{VCXOSTB}$	From power valid		10		ms
PLL Stabilization Time *	t_{PLLSTB}	From VCXO stable		500		us

5.0 Package Information

Table 7: 8-pin SOIC (0.150") Package Dimensions

	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.061	0.068	1.55	1.73
A1	0.004	0.0098	0.102	0.249
A2	0.055	0.061	1.40	1.55
B	0.013	0.019	0.33	0.49
C	0.0075	0.0098	0.191	0.249
D	0.189	0.196	4.80	4.98
E	0.150	0.157	3.81	3.99
e	0.050 BSC		1.27 BSC	
H	0.230	0.244	5.84	6.20
h	0.010	0.016	0.25	0.41
L	0.016	0.035	0.41	0.89
Θ	0°	8°	0°	8°

ALL RADII: 0.005" TO 0.01"

Table 8: 8-pin SOIC (0.150") Package Characteristics

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	TYP.	UNITS
Thermal Impedance, Junction to Free-Air 8-pin 0.150" SOIC	Θ_{JA}	Air flow = 0 m/s	110	°C/W
Lead Inductance, Self	L ₁₁	Corner lead	2.0	nH
		Center lead	1.6	
Lead Inductance, Mutual	L ₁₂	Any lead to any adjacent lead	0.4	nH
Lead Capacitance, Bulk	C ₁₁	Any lead to V _{SS}	0.27	pF

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6.0 Ordering Information

ORDERING CODE	DEVICE NUMBER	PACKAGE TYPE	OPERATING TEMPERATURE RANGE	SHIPPING CONFIGURATION
11640-804	FS6182-01	8-pin (0.150") SOIC (Small Outline Package)	0°C to 70°C (Commercial)	Tape and Reel
11640-814	FS6182-01	8-pin (0.150") SOIC (Small Outline Package)	0°C to 70°C (Commercial)	Tubes

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